Nch 600V 20A Power MOSFET

V _{DSS}	600V
R _{DS(on)} (Max.)	0.196Ω
I _D	±20A
P _D	231W

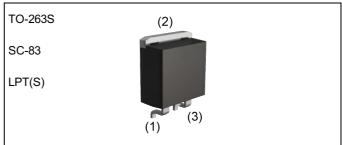
● Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Gate-source voltage (V_{GSS}) guaranteed to be ±20V.
- 4) Drive circuits can be simple.
- 5) Parallel use is easy.
- 6) Pb-free lead plating; RoHS compliant

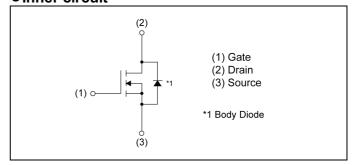
Application

Switching

Outline



•Inner circuit



Packaging specifications

	Packing	Embossed Tape
	Reel size (mm)	330
Туре	Tape width (mm)	24
	Quantity (pcs)	1000
	Taping code	TL
	Marking	R6020ENJ

● **Absolute maximum ratings** (T_a = 25°C ,unless otherwise specified)

Parameter	Symbol	Value	Unit	
Drain - Source voltage		V_{DSS}	600	V
Continuous drain current	T _C = 25°C	I _D *1	±20	А
	T _C = 100°C	I _D *1	±10.9	А
Pulsed drain current	I _{DP} *2	±60	А	
Gate - Source voltage	static	V	±20	V
	AC(f>1Hz)	V_{GSS}	±30	V
Avalanche current, repetitive	·	I _{AR}	3.4	А
Avalanche energy, single pulse		E _{AS} *3	418	mJ
Avalanche energy, repetitive		E _{AR} *3	0.63	mJ
Power dissipation (T _C = 25°C)	P _D *4	231	W	
Junction temperature	T _j	150	°C	
Operating junction and storage ten	nperature range	T _{stg}	-55 ~ +150	°C

● Absolute maximum ratings (T_a = 25°C)

Parameter	Symbol	Conditions	Values	Unit
Reverse diode dv/dt	dv/dt	-	15	V/ns
Drain - Source voltage slope	dv/dt	V _{DS} = 480V, T _j = 25°C	50	V/ns

●Thermal resistance

Doromotor	Cumb of	Values			Llmit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R _{thJC}	-	-	0.54	°C/W
Thermal resistance, junction - ambient	R _{thJA} *5	-	-	80	°C/W
Soldering temperature, wavesoldering for 10s	T _{sold}	1	1	265	°C

● Electrical characteristics (T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit
r ai ai netei	Symbol	Conditions	Min.	Тур.	Max.	Offic
Drain - Source breakdown voltage	V _{(BR)DSS}	$V_{GS} = 0V$, $I_D = 1mA$	600	-	-	V
		V _{DS} = 600V, V _{GS} = 0V				_
Zero gate voltage drain current	I _{DSS}	T _j = 25°C	-	0.1	100	μΑ
		T _j = 125°C	-	-	1000	
Gate - Source leakage current	I _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	±100	nA
Gate threshold voltage	V _{GS(th)}	V _{DS} = 10V, I _D = 1mA	2	-	4	V
		V _{GS} = 10V, I _D = 9.5A				
Static drain - source on - state resistance	R _{DS(on)} *6	T _j = 25°C	-	0.170	0.196	Ω
on state resistance		T _j = 125°C	-	0.360	-	
Gate resistance	R _G	f =1MHz, open drain	-	5.8	-	Ω

● Electrical characteristics (T_a = 25°C)

Davanastan	Currente e l	Conditions	Values			l leit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Forward Transfer Admittance	Y _{fs} *6	V _{DS} = 10V, I _D = 10A	5	10	-	S
Input capacitance	C _{iss}	V _{GS} = 0V	-	1400	-	
Output capacitance	C _{oss}	V _{DS} = 25V	-	1200	-	pF
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	130	-	
Effective output capacitance, energy related	C _{o(er)}	V _{GS} = 0V	-	56	-	
Effective output capacitance, time related	C _{o(tr)}	V _{DS} = 0V to 480V	-	266	-	pF
Turn - on delay time	t _{d(on)} *6	V _{DD} ≃ 480V,V _{GS} = 10V	-	35	-	
Rise time	t _r *6	I _D = 10A	-	53	-	
Turn - off delay time	t _{d(off)} *6	$R_L \simeq 48\Omega$	-	150	-	ns
Fall time	t _f *6	$R_G = 10\Omega$	-	67	-	

● Gate charge characteristics (T_a = 25°C)

Parameter	0 1 1	Conditions	Values			1.1:4
	Symbol	Conditions	Min.	Тур.	Max.	Unit
Total gate charge	Q _g *6	V _{DD} ≃ 480V,	-	60	-	
Gate - Source charge	Q _{gs} *6	I _D = 20A,	-	8	-	nC
Gate - Drain charge	Q _{gd} *6	V _{GS} = 10V	-	33	-	
Gate plateau voltage	V _(plateau)	V _{DD} = 480V, I _D = 20A	-	6.9	-	V

^{*1} Limited only by maximum channel temperature allowed.

^{*2} Pw ≤ 10µs, Duty cycle ≤ 1%

^{*3} L \doteqdot 70mH, V_{DD}=50V, R_G=25 Ω , STARTING T_i=25 $^{\circ}$ C

^{*4} T_C=25°C

^{*5} Mounted on a epoxy PCB FR4 (25mm x 27mm x 0.8mm)

^{*6} Pulsed

● Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Continuous forward current	I _S *1	T _c = 25°C	1	-	20	А
Pulse forward current	l _{SP} *2	1 _c - 25 C	-	-	60	А
Forward voltage	V _{SD} *6	V _{GS} = 0V, I _S = 20A	-	-	1.5	V
Reverse recovery time	t _{rr} *6		1	550	-	ns
Reverse recovery charge	Q _{rr} *6	I _S = 20A, V _{GS} =0V di/dt = 100A/µs	-	10.4	-	μC
Peak reverse recovery current	I _{mm} *6	α,, ατ 100/ τρο	-	38	-	Α

Typical Transient Thermal Characteristics

Symbol	Value	Unit	Symbol	Value	Unit
R _{th1}	0.068	_	C _{th1}	0.00213	
R _{th2}	0.261	K/W	C _{th2}	0.00766	Ws/K
R _{th3}	0.607		C _{th3}	0.195	

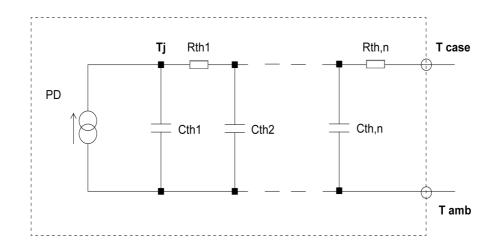


Fig.1 Power Dissipation Derating Curve

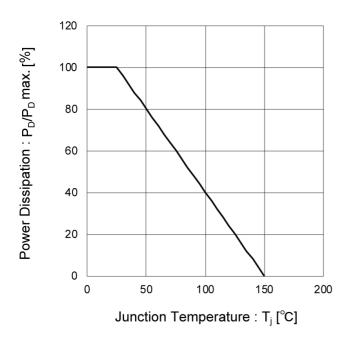
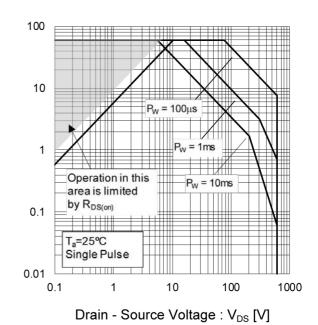


Fig.2 Maximum Safe Operating Area



Drain Current : I_D [A]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

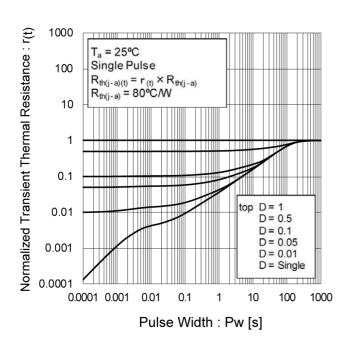
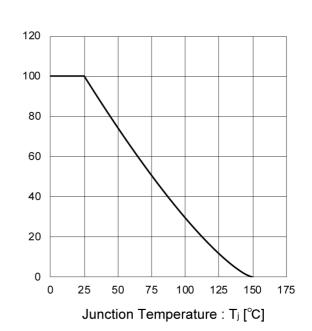


Fig.4 Avalanche Energy Derating
Curve vs. Junction Temperature



Avalanche Energy : E_AS / E_AS max [%]

Fig.5 Typical Output Characteristics(I)

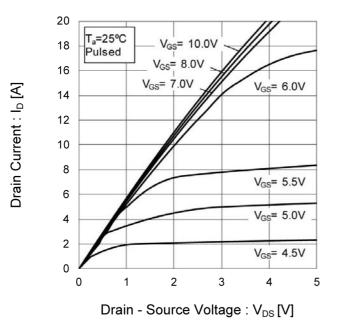
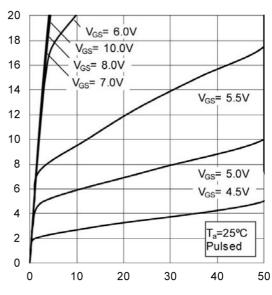


Fig.6 Typical Output Characteristics(II)



Drain Current : I_D [A]

Drain - Source Voltage : V_{DS} [V]

Fig.7 Tj = 150°C Typical Output Characteristics (I)

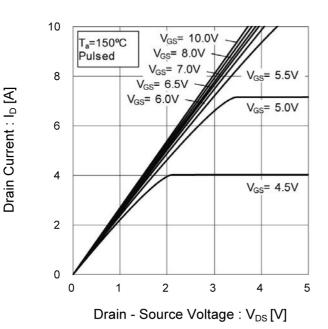
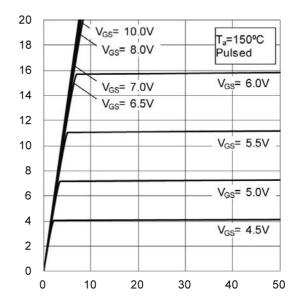


Fig.8 Tj = 150°C Typical Output Characteristics (II)



Drain - Source Voltage: V_{DS}[V]

Drain Current : I_D [A]

Fig.9 Breakdown Voltage vs.

Junction Temperature

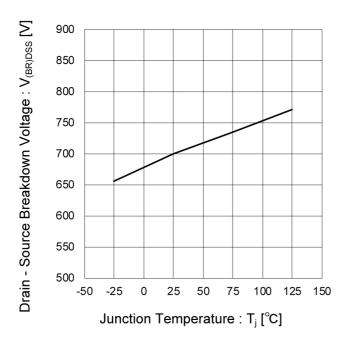


Fig.10 Typical Transfer Characteristics

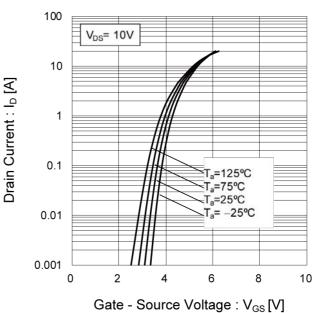


Fig.11 Gate Threshold Voltage vs.

Junction Temperature

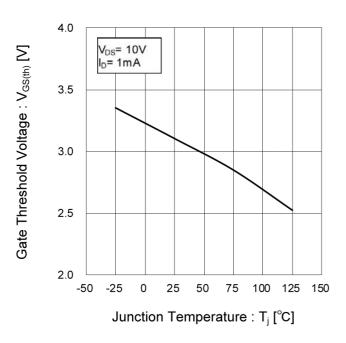


Fig.12 Forward Transfer Admittance vs.
Drain Current

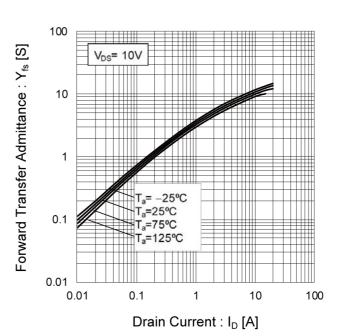


Fig.13 Static Drain - Source On - State Resistance vs. Gate Source Voltage

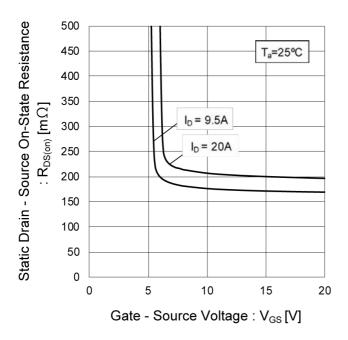


Fig.14 Static Drain - Source On - State
Resistance vs. Junction Temperature

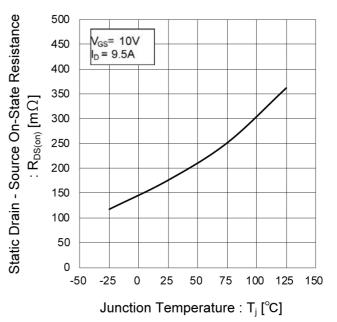


Fig.15 Static Drain - Source On - State Resistance vs. Drain Current(I)

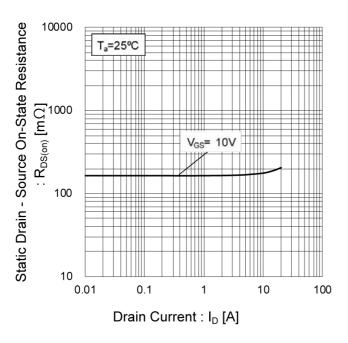


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current(II)

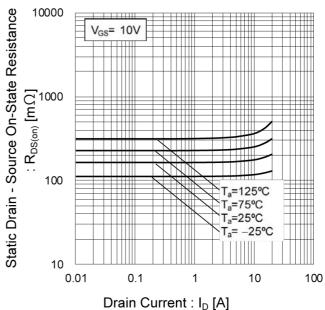


Fig.17 Typical Capacitance vs.

Drain - Source Voltage

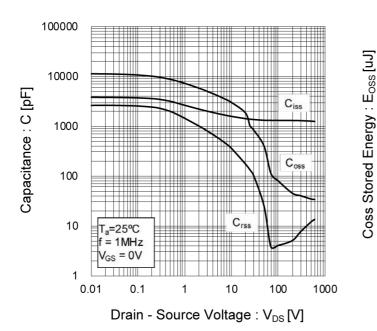


Fig.18 Coss Stored Energy

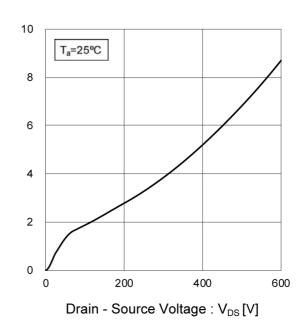


Fig.19 Switching Characteristics

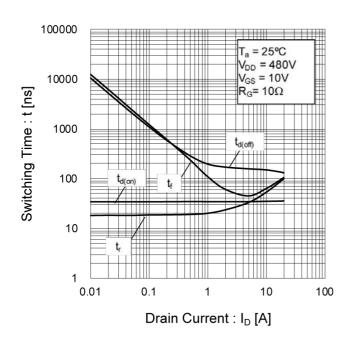
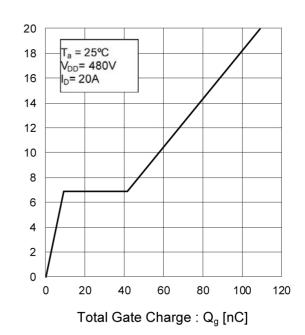


Fig.20 Dynamic Input Characteristics



Gate - Source Voltage : V_{GS} [V]

Fig.21 Inverse Diode Forward Current vs. Source - Drain Voltage

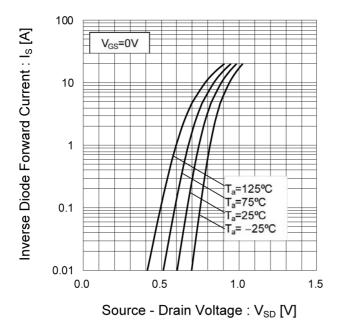
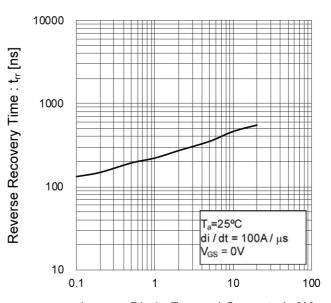


Fig.22 Reverse Recovery Time vs.
Inverse Diode Forward Current



Inverse Diode Forward Current : I_S [A]

Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

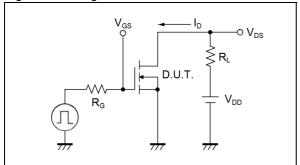


Fig.2-1 Gate Charge Measurement Circuit

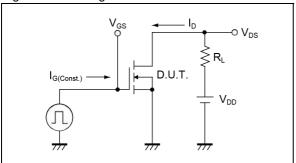


Fig.3-1 Avalanche Measurement Circuit

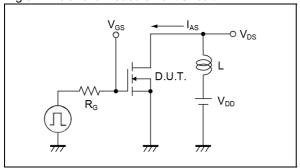


Fig.4-1 dv/dt Measurement Circuit

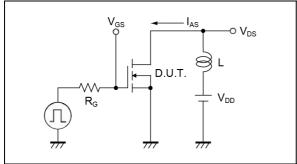


Fig.5-1 dv/dt Measurement Circuit

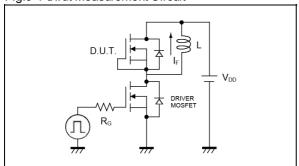


Fig.1-2 Switching Waveforms

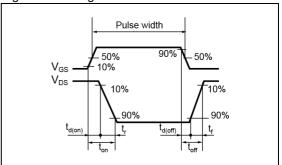


Fig.2-2 Gate Charge Waveform

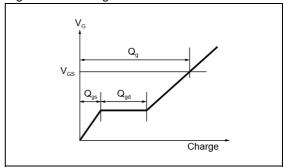


Fig.3-2 Avalanche Waveform

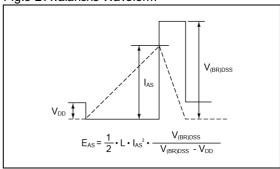


Fig.4-2 dv/dt Waveform

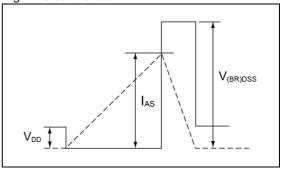
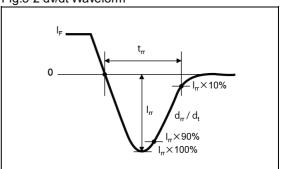
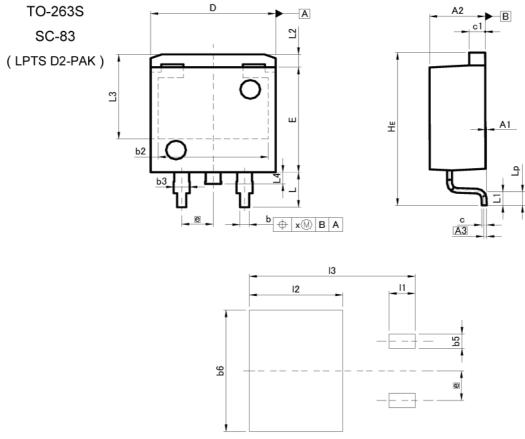


Fig.5-2 dv/dt Waveform



Dimensions



Pattern of terminal position areas [Not a pattern of soldering pads]

DIM	MILIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
A1	0.00	0.30	0.000	0.012
A2	4.30	4.70	0.169	0.185
A3	0.	25	0.0	10
b	0.68	0.98	0.027	0.039
b2	8.	90	0.3	350
b3	1.14	1.44	0.045	0.057
С	0.30	0.60	0.012	0.024
c1	1.10	1.50	0.043	0.059
D	9.80	10.40	0.386	0.409
E	8.80	9.20	0.346	0.362
е	2.	54	0.100	
HE	12.80	13.40	0.504	0.528
L	2.70	3.30	0.106	0.130
L1	1.	20	0.047	
L2	1.	10	0.043	
L3	7.	7.25		285
L4	1.00		0.039	
Lp	0.90	1.50	0.035	0.059
Х	= 3	0.25		0.010
S 22.4	MILIM	FTFRS	I INC	HES

DIM	MILIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
b5	-	1.23	-	0.049
b6	=7	10.40		0.409
- 11	<u> </u>	2.10	, 72	0.083
12	-	7.55	155	0.297
13	-	13.40	·-	0.528

Dimension in mm/inches



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JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSII	CLASS II b	CLASSIII
CLASSIV		CLASSⅢ	

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 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
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 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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 - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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Notice-PGA-E Rev.004

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TPCC8103,L1Q(CM MIC4420CM-TR VN1206L 614234A 715780A NTNS3166NZT5G SSM6J414TU,LF(T 751625C

IPS70R2K0CEAKMA1 BUK954R8-60E DMN3404LQ-7 NTE6400 SQJ402EP-T1-GE3 2SK2614(TE16L1,Q) 2N7002KW-FAI

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